

Dual P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
	0.015 at V _{GS} = - 4.5 V	- 9.4			
- 20	0.019 at V _{GS} = - 2.5 V	- 8.4			
	0.024 at V _{GS} = - 1.8 V	- 7.5			

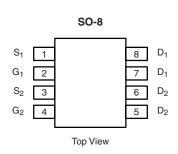
FEATURES

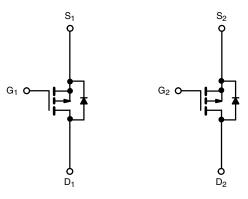
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

· Load Switching





P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	$T_A = 25$ °C, unles	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 20		V
Gate-Source Voltage		V _{GS}	± 8		٧
0 11 0 1 (7 150 00)8	T _A = 25 °C	- I _D	- 9.4	- 7.1	^
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 7.5	- 5.7	
Pulsed Drain Current		I _{DM}	- 30		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 1.7	- 0.9	
	T _A = 25 °C	В	2.0	1.1	W
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	1.3	0.7	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 t	o 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana kantina ta Andrina 18	t ≤ 10 s	D	45	62.5	
Maximum Junction-to-Ambient ^a	Steady State	- R _{thJA}	85	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	26	35	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



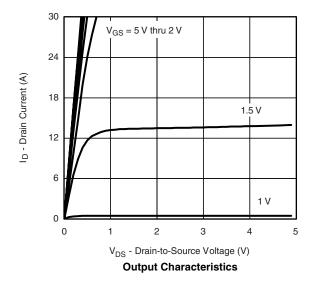
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -500 \mu A$	- 0.40		- 1.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvaia Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current		$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	C -5		- 5	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 30			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -9.4 \text{ A}$		0.0125	0.015		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -8.4 \text{ A}$		0.0155	0.019	Ω	
		V _{GS} = - 1.8 V, I _D = - 3.0 A		0.020	0.024		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 9.4 A		40		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.7	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			43	65		
Gate-Source Charge	Q _{gs}	Q_{gs} $V_{DS} = 10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_D = -9.4 \text{ A}$		7.1		nC	
Gate-Drain Charge	Q_{gd}			10.9		1	
Turn-On Delay Time	t _{d(on)}			32	50		
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		42	65		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 4.5 V, R_g = 6 Ω		350	525	ns	
Fall Time	t _f			160	240		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs		127	200		

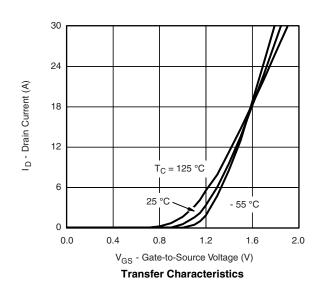
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

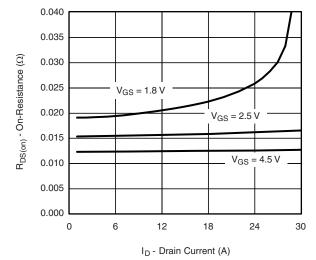
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



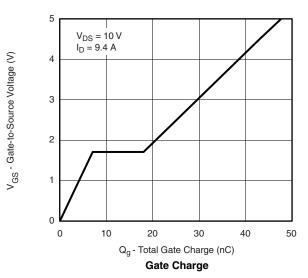


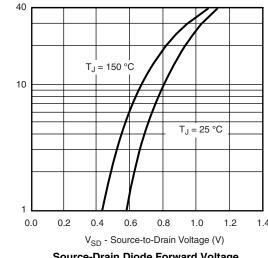


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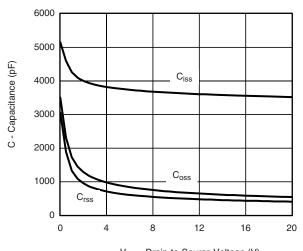
On-Resistance vs. Drain Current





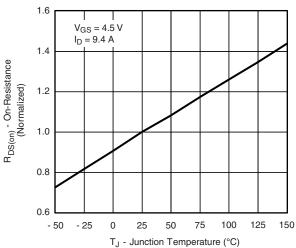
I_S - Source Current (A)

Source-Drain Diode Forward Voltage

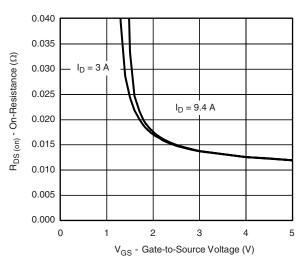


V_{DS} - Drain-to-Source Voltage (V)

Capacitance



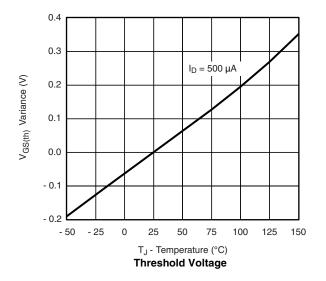
On-Resistance vs. Junction Temperature

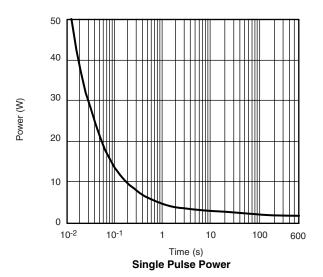


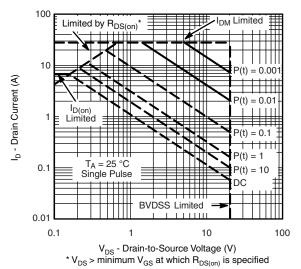
On-Resistance vs. Gate-to-Source Voltage



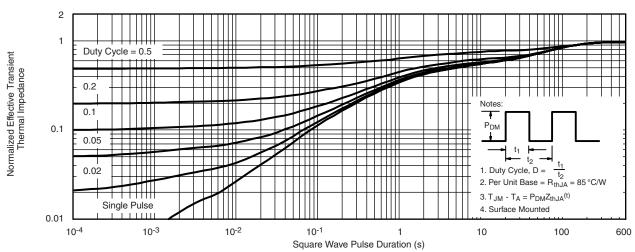
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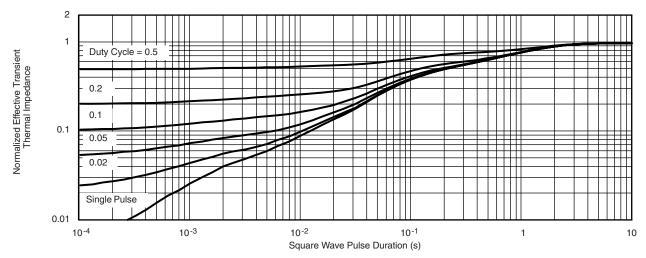






Normalized Thermal Transient Impedance, Junction-to-Ambient

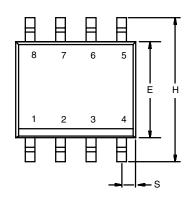
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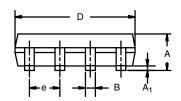


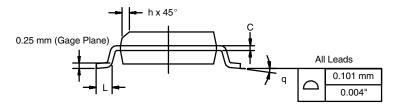
Normalized Thermal Transient Impedance, Junction-to-Foot



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







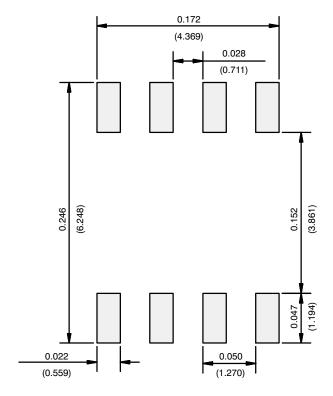
	MILLIM	IETERS	INC	HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
FCN: C-06527-Bey I 11-Sen-06						

ECN: C-06527-Rev. I, 11-Sep-06

DWG: 5498



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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